

12500 TI Boulevard, MS 8640, Dallas, Texas 75243

PCN# 20180622001.1 Qualification of DMOS6 as an additional Wafer Fab Site option for select devices Change Notification / Sample Request

Date: June 25, 2018

To: PREMIER FARNELL PCN

Dear Customer:

This is an announcement of a change to a device that is currently offered by Texas Instruments. The details of this change are on the following pages.

We request you acknowledge receipt of this notification within **30** days of the date of this notice. Lack of acknowledgement of this notice within 30 days constitutes acceptance of the change. If you require samples or additional data to support your evaluation, please request within 30 days.

The changes discussed within this PCN will not take effect any earlier than **90** days from the date of this notification, unless customer agreement has been reached on an earlier implementation of the change. This notification period is per TI's standard process.

This notice does not change the end-of-life status of any product. Should product affected be on a previously issued product withdrawal/discontinuance notice, this notification does not extend the life of that product or change the life time buy offering/discontinuance plan.

For questions regarding this notice, contact your local Field Sales Representative or the PCN Manager (PCN www admin team@list.ti.com).

PCN Team SC Business Services

20180622001.1 Attachment: 1

Products Affected:

The devices listed on this page are a subset of the complete list of affected devices. According to our records, these are the devices that you have purchased within the past twenty-four (24) months. The corresponding customer part number is also listed, if available.

DEVICE CC2564CRVMT **CUSTOMER PART NUMBER**

null

Technical details of this Product Change follow on the next page(s).

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				0180622001.1					N Date:	Jun 25, 2018	
Title:	Qualification of DMOS6 as an additional Wafer Fab Site option for select devices in C021 Technology										
Customer	Contac	:t:	<u>P(</u>	CN Managei	_		Dept:		Quality	Services	
Proposed 1 st Ship Date:			S	Sep 25, 2018		Estimated Sample Availability:			Date provided at sa request.		
Change T	ype:						_		•		
Assembly Site				Assembly Process					Assembly Materials		
Design				Electrical Specification					Mechanical Specification		
Test S				Packing/Shipping/Labeling			g		Test Process		
Wafer	Bump S	Site		Wafer Bump Material				Wafer Bump Process			
Wafer	Fab Site	9		Wafer Fab Materials				Wafer Fal	o Process		
				Part nun	nber c	hange					
			<u> </u>	•		Details					
Description	on of Ch	ange									
			to an	nounce the	additi	on of DMOS	S6 as an a	addit	ional Wafe	er Fab site option	
_						ction of this			ional war	or rab site option	
Current		ab Site		Process			Wafer		neter		
TSMC-F14	TSMC-F14			C021			300mm	1			
Addition	Additional Fab Site			Process			Wafer	Dia	meter		
DMOS6	ai i ab c	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,					Wafer Diameter				
				C021 300mm			1				
Reason fo	r Chang	ge:									
Continuity	of Supp	ly									
Anticipate	ed impa	ct on F	orm,	Fit, Functi	ion, Q	uality or R	eliability	y (po	ositive /	negative):	
None											
Changes t	to produ	uct ider	ntifica	ation resu	lting 1	rom this F	CN:				
	<u> </u>										
Current											
Chip Site	Chip Site Chip Site			igin (20L)	Chip	Site Count	ry Code (21L)	Chip S	Site City	
TSMC-F14	SMC-F14 T14				TWN				Tainar	n City	
	Į.				1					,	
Now Esh	Sito										
New Fab Chip Site	Site	Chin Ci	ito Or	igin (20L)	Chin	Site Count	m. Codo (211)	Chin C	Site City	
l -			ite Oi	igili (ZUL)			ry Code (ZIL)	•		
DMOS6		DM6			USA				Dallas		
Sample pro	oduct sh	ipping la	abel (not actual p	oroduc	t label)					
₩ TEXA	45		(Pb)	600623		1	01741.07	27116	. n		
INSTRUM	MENTS		G4	Crais	4100	35 (1P) 31:	SN74LS(J/N	ok		
MADE IN: 2DC:	Malaysi 20:	ia		10000		在 (Q)	2000	([·) 0336		
MSL 2 /260C/1 YEAR SEAL DT											
MSL 1 /235C/UNLIM 03/29/04 (4W) TKY(1T) 7523483SI2											
ITEM: 39 (2F) REV: (V) 0033317											
LBL: 5	LBL: 5A (L) TO: 1750 (22L) CSO: SHE (21L) CCO: USA (22L) ASO: MLA (23L) ACO: MYS										
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Droduct A	ffootod	Group	•								
Product A						1			T		
CC2564CRVMR C			CC256	54CRVMT		CC2564C	YFVR		CC25640	CYFVT	

Qualification Report

Orca CC256x ROM C Product Qualification for QFN Fab: TSMC14 & TI – DMOS6 Assembly Sites: Amkor K1 & Amkor P1 for QFN, Clark for WCSP Approved 04/04/2018

Product Attributes

	Qual Device 1: BL6450QRVMR	Qual Device 2: BL6450QRVMR	Qual Device 3: BL6450QVRM	Qual Device 4: XCC2567YFVT
Assembly Site	AMKOR K1	AMKOR P1	AMKOR P1	Clark
Package Family	QFN	QFN	QFN	WCSP
Flammability Rating				
Wafer Fab Supplier	TSMC-F14	TSMC-F14	DMOS6	DMOS6
Wafer Fab Process	1218C021.M6	1218C021.M6	1218C021.M6	1218C021.M6

- QBS: Qual By Similarity
- Qual Device BL6450QRVMR is qualified at LEVEL3-260C
- Qual Device XCC2567YFVT is qualified at LEVEL1-260C

Qualification Results

Data Displayed as: Number of lots/Total sample size/Total failed

Туре	Test Name / Condition	Duration	Qual Device 1: BL6450QRVMR	Qual Device 2: BL6450QRVMR	Qual Device 3: BL6450QRVM	Qual Device 4: XCC2567YFVT
THB	Temperature and Humidity Bias, 85C/85%RH	1000 Hours	3/231/0	3/233/0	2/154/0	3/86/0
UHAST	Unbiased Humidity, 110C/85% RH	264 Hours	3/231/0	-	3/231/0	-
UHAST	Unbiased Humidity, 130C/85% RH	96 Hours	-	3/234/0	-	3/230/0
TC	Thermal Cycle, -55/125C	1000 Cycles	3/230/0	-	3/231/0	3/230/0
HTSL	High Temperature Storage Bake, 150C	1000 Hours	3/231/0	3/234/0	1/45/0	3/231/0
HTOL	Life Test, 125C	1000 Hours	3/230/0	-	3/231/0	-
WBS	Wire Bond Shear	(Cpk>1.67)	-	Pass	Pass	NA
WBP	Wire Bond Pull	(Cpk>1.67)	-	Pass	Pass	NA
PD	Physical Dimensions	(Cpk>1.67)	-	Pass	Pass	Pass
HBM	ESD-HBM	500V	1/3/0	-	1/3/0	1/3/0
CDM	ESD-CDM	250V	-	-	1/3/0	1/3/0
LU	Latch-up, High Temp	+/- 100 mA and 1.5 x Vmax @ max Jj	3/18/0	-	1/3/0	-
MQ	Manufacturability	(per mfg. Site specification)	Pass	Pass	Pass	Pass

⁻ Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

- The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles Quality and Environmental data is available at Tl's external Web site: http://www.ti.com/

This Quality and Reliability Report is provided strictly "AS IS", with all faults, and without any warranty, express or implied. All data relating to product performance under the conditions described herein are estimations only. Product information detailed in this Report may not accurately reflect TI's current product materials, processes and testing used in the construction of the TI products.

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For questions regarding this notice, e-mails can be sent to the regional contacts shown below, or you can contact your local Field Sales Representative.

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